



IRL6372PBF Information



For Reference Only

Part Number IRL6372PBF

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

DescriptionMOSFET 2N-CH 30V 8.1A 8SO**Package**8-SOIC (0.154", 3.90mm Width)

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRL6372PBF Specifications

Manufacturer Part Number	IRL6372PBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	HEXFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	8.1A
Rds On (Max) @ Id, Vgs	17.9 mOhm @ 8.1A, 4.5V
Vgs(th) (Max) @ Id	1.1V @ 10μA
Gate Charge (Qg) (Max) @ Vgs	11nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1020pF @ 25V
Power - Max	2W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

IRL6372PBF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRL6372PBF Payment Methods



















IRL6372PBF Shipping Methods













If you have any question about IRL6372PBF, please do not hesitate to contact us!

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